NEWS & VIEWS

Open Access

Persistent X-ray-activated phosphors: mechanisms and applications

Cyrille Richard^{1 ™} and Bruno Viana^{2 ™}

Abstract

Trivalent lanthanides in wide bandgap fluoride or phosphate hosts can present persistent luminescence between 200 nm and 1.7 µm after charging by X-rays. Mechanisms are reviewed and applications envisioned.

Persistent luminescence is controlled by a slow liberation of trapped charge carriers at body temperature by a simple thermal de-excitation process. It can last for a few minutes to hours after the removal of the excitation source. The persistent luminescence mechanisms can be envisioned from Physics or Chemistry points of view. With material Chemistry vision, two main strategies are envisioned for the trapping process which is the initial and very important step: first, the intrinsic defects and the optimization of the trapping by stoichiometric variation and thermal annealing, and second, a trap optimization by codoping. This latter strategy has been intensively tested to enhance the persistent luminescence, most of the time by co-doping with one or two lanthanides cations. Following these two distinctive approaches, the physics behind the persistent luminescence mechanisms is not simple and several different models have been proposed during the past years¹⁻⁶. A *global model* in which the transfer of the trapped/detrapped charges occurs through the conduction or valence bands, or with both⁷. In that case, block functions of the carriers are delocalized and indeed this model can be named a global model⁸. Materials with intermediate bandgap values ranging between 3 and 7 eV such as sulfide, oxysulfide, and oxides, namely, garnets, gallate, phosphates, aluminates., etc. required ultraviolet (UV)/

Correspondence: Cyrille Richard (cyrille.richard@u-paris.fr) or

Bruno Viana (bruno.viana@chimieparistech.fr)

blue light for efficient charging through the bandgap and in that case, the so-called bandgap engineering could generally be applied^{1,7,9}. On the contrary, a *local model* considers a direct electron transfer between activator and trapping centers^{10,11}. Arguments for the two models are now well established and the energy required for the charging process, for instance, could control the process: high energy for global model while low energy is associated with local defect such as antisites, for instance, that are well established in garnets^{12–15}, perovskite¹⁶, and spinel materials^{17,18}. Calculations as proposed in ref. ¹⁹ further validate the so-called *local model*.

Very recently, X-rays have been used as charging light in various materials. In materials that could also be charged by UV or/and visible light such as ZnGa₂O₄:Cr, but also in wide bandgap materials which cannot be charged by usual lamps due to their large bandgap $(>12 \text{ eV})^{20}$. These materials are mainly fluorides such as $NaLnF_4$ (Ln = Lu, Y, Gd, La) with bandgap values in the range $12-14 \text{ eV}^{21,22}$. In that case, local trapping and detrapping model could well explain the observed persistent luminescence. Li et al. described the local defects in wide bandgap materials such as in NaYF₄:Ln³⁺-doped materials with anions vacancies²² created under X-ray charging. Notice that the efficiency of such charging can be very high in these nanomaterials as measured in Na $(Gd,Lu)F_4$:Tb³⁺ to be 2.8×10^{16} photons/g²³, which is surprisingly high for nano-sized particles and comparable to the commercial SrAl₂O₄:Eu²⁺,Dy³⁺ bulk persistent phosphor where the global model is the most relevant (de)trapping model. Another remarkable example of local

Open Access This article is licensed under a Creative Commons Attribution 4.0 International License, which permits use, sharing, adaptation, distribution and reproduction in any medium or format, as long as you give appropriate credit to the original author(s) and the source, provide a link to the Creative Commons license, and indicate if changes were made. The images or other third party material in this article are included in the article's Creative Commons license, unless indicated otherwise in a credit line to the material. If material is not included in the article's Creative Commons license and your intended use is not permitted by statutory regulation or exceeds the permitted use, you will need to obtain permission directly from the copyright holder. To view a copy of this license, visit http://creativecommons.org/licenses/by/4.0/.

¹Université Paris Cité, CNRS, INSERM, UTCBS, Unité de Technologies Chimiques et Biologiques pour la Santé, Faculté de Pharmacie, 75006 Paris, France ²IRCP, CNRS UMR8247, PSL University, Chimie ParisTech, 11 Rue P&M Curie, 75005 Paris, France

[©] The Author(s) 2022



defect is presented in Nd, Ho, Tm, and Er:NaYF₄@NaYF₄ core-shell nanoparticles in ref.²⁴. Fluoride vacancies and/or fluoride Frenkel defects (vacancy-interstitial pairs) could be formed (see Fig. 2 in ref. ²⁴). Some controversy still remains for these wide-bandgap hosts as in another recent work, Zhuang et al.²⁵ explain (see Fig. 2a, b in ref.²⁵) that the persistent luminescence mechanism occurs by global model but notice that there is some discrepancy in the bandgap value of NaYF₄ fluoride host, 13 eV reported in ref.²¹ (see SI7 in ref.²¹) in regard to 12 eV in²⁵, while charge carriers are not easily delocalized in these compounds. Furthermore, as reported by Li et al.²², global model cannot well explain the persistent luminescence for the fluoride hosts doped with Gd^{3+} , then efforts are still required to better model this amazing phenomenon taking into account either a Physics or material Chemistry point of view.

Through an appropriate selection of the Ln^{3+} element in the synthesis of fluoride or phosphate hosts, a wide range of persistent luminescence emission, from 200 nm up to 1.7 µm, can be obtained after X-ray excitation (30 mA, 40 kV). Since the photon counts are much higher when materials are exposed to X-rays when compared to another light source, persistent phosphors developed by Li et al. should have many applications²² among those listed in Fig. 1.

UV light irradiation in the 200–400 nm region may pose considerable phototoxicity to living cells. One way to

solve this problem is to use materials that are excited at smaller wavelengths while emitting deep UV. Ce^{3+} or Gd^{3+} -doped NaYF₄ have the capability of UV emission at 250 or 300 nm after being excited by X-rays. Such phosphors are likely to find applications, for example, in photoclick chemistry for which high energy over a long time is needed to create covalent bonds²⁶. But other applications for which high energy is required could also be envisioned, such as sterilization and disinfection²⁷.

When moving to the visible range, such presented X-ray-activated phosphors should also find applications either in vitro for the development of biosensors²⁸ or in vivo for imaging²⁹ as well as in therapy³⁰. Bioimaging applications can be improved when using probes emitting in BW-I (650–980 nm) or with nanoparticles emitting in BW-II (1000–1600 nm) since this allows imaging of deeper tissues and it gives access to images with better spatial resolution²⁴. Here again, the luminescent phosphors developed by Li et al. could be particularly useful. In addition to these applications in biology, many more applications of luminescent phosphors excited by X-rays can be envisioned not only for anti-counterfeiting, information storage, and security²⁵ but also in cryopreservation and photocatalysis³¹.

Published online: 04 May 2022

References

- Xu, J. & Tanabe, S. Persistent luminescence instead of phosphorescence: history, mechanism, and perspective. J. Lumin. 205, 581–620 (2019).
- Li, Y., Gecevicius, M. & Qiu, J. R. Long persistent phosphors from fundamentals to applications. *Chem. Soc. Rev.* 45, 2090–2136 (2016).
- Brito, H. F. et al. Persistent luminescence mechanisms: human imagination at work. Optical Mater. Express 2, 371–381 (2012).
- Joos, J. J. et al. Identification of Dy³⁺/Dy²⁺ as electron trap in persistent phosphors. *Phys. Rev. Lett.* **125**, 033001 (2020).
- Bessière, A. et al. How to induce red persistent luminescence in biocompatible Ca₃(PO₄)₂. J. Mater. Chem. C 1, 1252–1259 (2013).
- Xu, J. et al. Y₃Al_{5-x}Ga_xO₁₂Cr³⁺: a novel red persistent phosphor with high brightness. Appl. Phys. Express 8, 042602 (2015).
- Lyu, T. S. & Dorenbos, P. Bi³⁺ acting both as an electron and as a hole trap in La-, Y-, and LuPO₄. J. Mater. Chem. C 6, 6240–6249 (2018).
- Dorenbos, P. Mechanism of persistent luminescence in Eu²⁺ and Dy³⁺ codoped aluminate and silicate compounds. J. Electrochem. Soc. 152, H107–H110 (2005).
- 9. Ueda, J. et al. Development of white persistent phosphors by manipulating lanthanide ions in gadolinium gallium garnets. *Adv. Photonics Res.* **2**, 2000102 (2021).
- Clabau, F. et al. Formulation of phosphorescence mechanisms in inorganic solids based on a new model of defect conglomeration. *Chem. Mater.* 18, 3212–3220 (2006).
- Bessière, A. et al. Storage of visible light for long-lasting phosphorescence in chromium-doped zinc gallate. *Chem. Mater.* 26, 1365–1373 (2014).
- Stanek, C. R. et al. The effect of Ga-doping on the defect chemistry of RE₃Al₅O₁₂ garnets. *Phys. Status Solidi (B)* **250**, 244–248 (2013).
- Ashurov, M. K. et al. Spectroscopic study of stoichiometry deviation in crystals with garnet structure. *Phys. Status Solidi* (A) 42, 101–110 (1977).
- Kamada, K et al. Cz grown 2-in. size Ce:Gd₃(Al,Ga)₅O₁₂ single crystal; relationship between Al, Ga site occupancy and scintillation properties. *Optical Mater.* 36, 1942–1945 (2014).
- 15. Fasoli, M. et al. Band-gap engineering for removing shallow traps in rare-earth $Lu_3Al_5O_{12}$ garnet scintillators using Ga³⁺ doping. *Phys. Rev. B* **84**, 081102 (2011).

- Casillas-Trujillo, L. et al. Intrinsic defects, nonstoichiometry, and aliovalent doping of A²⁺B⁴⁺O₃ perovskite scintillators. *Phys. Status Solidi (B)* **251**, 2279–2286 (2014).
- Maldiney, T. et al. The in vivo activation of persistent nanophosphors for optical imaging of vascularization, tumours and grafted cells. *Nat. Mater.* 13, 418–426 (2014).
- 18. Basavaraju, N. et al. The importance of inversion disorder in the visible light induced persistent luminescence in Cr^{3+} doped AB_2O_4 (A = Zn or Mg and B = Ga or Al). *Phys. Chem. Chem. Phys.* **17**, 1790–1799 (2015).
- De Vos, A. et al. First-principles study of antisite defect configurations in ZnGa₂O₄:Cr persistent phosphors. *Inorg. Chem.* 55, 2402–2412 (2016).
- Song, L. et al. Low-dose X-ray activation of W(VI)-doped persistent luminescence nanoparticles for deep-tissue photodynamic therapy. *Adv. Funct. Mater.* 28, 1707496 (2018).
- Mandl, G. A. et al. On a local (de-)trapping model for highly doped Pr³⁺ radioluminescent and persistent luminescent nanoparticles. *Nanoscale* 12, 20759–20766 (2020).
- Li, L. P. et al. Mechanism of the trivalent lanthanides' persistent luminescence in wide bandgap materials. *Light. Sci. Appl.* **11**, 51 (2022).
- 23. Van der Heggen, D. et al. Optically stimulated nanodosimeters with high storage capacity. *Nanomaterials* **9**, 1127 (2019).
- Pei, P. et al. X-ray-activated persistent luminescence nanomaterials for NIR-II imaging. *Nat. Nanotechnol.* 16, 1011–1018 (2021).
- Zhuang, Y. X. et al. X-ray-charged bright persistent luminescence in NaYF₄: Ln³⁺@NaYF₄ nanoparticles for multidimensional optical information storage. *Light. Sci. Appl.* **10**, 132 (2021).
- 26. Fairbanks, B. D. et al. Photoclick chemistry: a bright idea. Chem. Rev. 121, 6915–6990 (2021).
- 27. Yang, Y. M. et al. X-ray-activated long persistent phosphors featuring strong UVC afterglow emissions. *Light. Sci. Appl.* **7**, 88 (2018).
- Liu, J. H. et al. Imaging and therapeutic applications of persistent luminescence nanomaterials. Adv. Drug Deliv. Rev. 138, 193–210 (2019).
- Zhu, W. J. et al. Low-dose real-time X-ray imaging with nontoxic double perovskite scintillators. *Light. Sci. Appl.* 9, 112 (2020).
- Chen, X. F. et al. X-ray-activated nanosystems for theranostic applications. Chem. Soc. Rev. 48, 3073–3101 (2019).
- Poelman, D. et al. Persistent phosphors for the future: fit for the right application. J. Appl. Phys. 128, 240903 (2020).